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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH16244FT

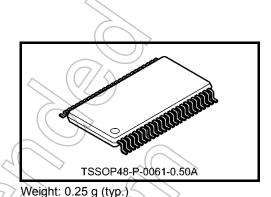
Low-Voltage 16-Bit Bus Buffer with Bushold

The TC74VCXH16244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the \overline{OE} input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The A data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Features

- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: $t_{pd} = 2.5 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
 - : $t_{pd} = 3.0 \text{ ns} (\text{max}) (\text{V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$

$$t_{pd} = 5.0 \text{ ns} (\text{max}) (\text{V}_{CC} = 1.8)$$

- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA} (\min) (V_{CC} = 3.0 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 18 \text{ mA} \text{ (min)} (V_{CC} = 2.3 \text{ V})$

 $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$

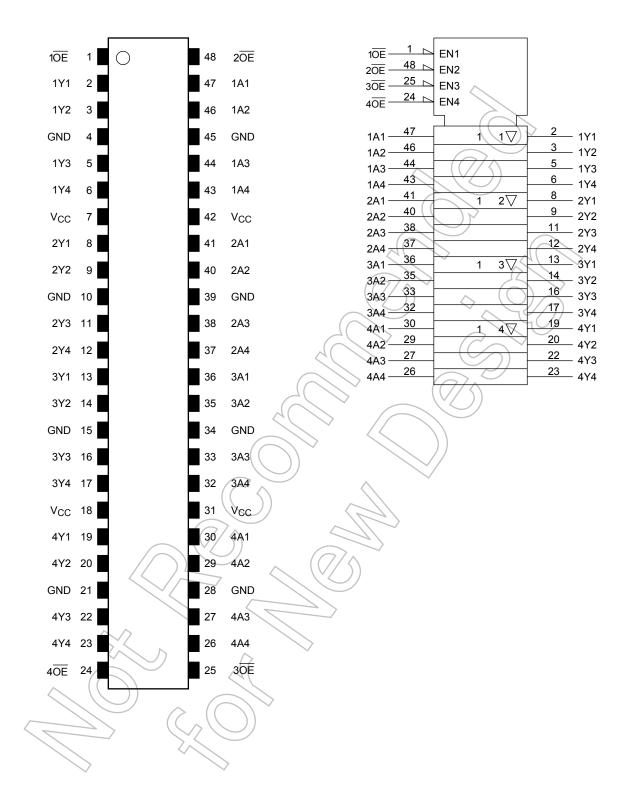
- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V
 - Human body model ≥ ±2000 V
- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs



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Pin Assignment (top view)

IEC Logic Symbol



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Truth Table

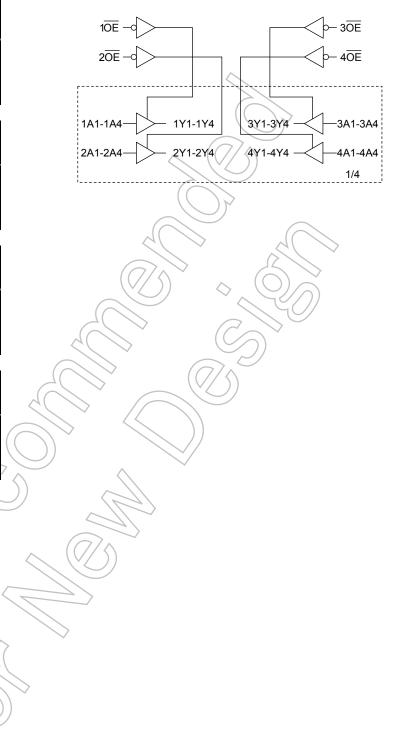
Inp	uts	Outputs
1 0E	1A1-1A4	1Y1-1Y4
L	L	L
L	Н	Н
Н	Х	Z

Inp	outs	Outputs
20E	2A1-2A4	2Y1-2Y4
L	L	L
L	н	н
Н	Х	Z

Inp	outs	Outputs
30E	3A1-3A4	3Y1-3Y4
L	L	L
L	н	Н
Н	Х	Z

Inp	uts	Outputs
40E	4A1-4A4	4Y1-4Y4
L	L	L
L	Н	Н
Н	Х	z

System Diagram



X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V _{CC}	-0.5 to 4.6	V	
	(OE)	Max	-0.5 to 4.6	V	
DC input voltage (An	(An)	VIN	-0.5 to V _{CC} + 0.5	v	
DC output voltage		Maria	-0.5 to 4.6 (Note 2)	V	
		Vout	–0.5 to V _{CC} + 0.5 (Note 3)		75
Input diode current		IIK	-50	MA	
Output diode current		I _{OK}	±50 (Note 4)	(mA)	>
Output current		IOUT	±50	mA	\frown
Power dissipation		PD	400	Wm	
DC V _{CC} /ground curren	t per supply pin	I _{CC} /I _{GND}	±100	→ mA	\mathcal{A}
Storage temperature		T _{stg}	-65 to 150	°C 🗸	(0)

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1) (Note 2)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		Vcc	1.8 to 3.6	V	
Power supply voltage		vcc	1.2 to 3.6 (Note 3)	v	
Input voltage	(OE)	Max	-0.3 to 3.6	V	$\langle \rangle$
Input voltage	(An)	V _{IN}	0 to V _{CC}	v	\mathcal{C}
Output voltage			0 to 3.6 (Note 4)	V	\mathcal{C}
Oulput voltage		Vout	0 to V _{CC} (Note 5)	ľ (C	7~
			±24 (Note 6)		$\bigcirc)$
Output current		I _{OH} /I _{OL}	±18 (Note 7)	mA	
			±6 (Note 8)	(\bigcirc)	7
Operating temperature		T _{opr}	-40 to 85	°C	
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: Floating or unused control inputs must be held high or low.

Note 3: Data retention

- Note 4: OFF state
- Note 5: High or low state
- Note 6: $V_{CC} = 3.0$ to 3.6 V
- Note 7: $V_{CC} = 2.3$ to 2.7 V
- Note 8: V_{CC} = 1.8 V
- Note 9: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < V_{CC} \leq 3.6 V)

Characteris	stics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
Innut voltage	H-level	VIH	—		2.7 to 3.6	2.0	_	V
Input voltage	L-level	VIL	_	_	2.7 to 3.6	1	0.8	v
H-level				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2		
	Vон	VIN = VIH or VIL	I _{OH} = -12 mA	2.7	2.2			
				I _{OH} = -18 mA	3.0	2.4	_	
				I _{OH} = -24 mA	3.0	2.2		V
				I _{OL} = 100 μA	2.7 to 3.6		0.2	
L-level		Vol	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 12 mA	2.7	Å	0.4	-
	L-IEVEI			I _{OL} = 18 mA	3.0	\geq	0.4	
				I _{OL} = 24 mA	3.0(() + (0.55	
Input leakage	(OE)	I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	Y)	±5.0	μA
current	(An)	١N	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	\geq	±5.0	μΛ
Bushold input minim	um drive		V _{IN} = 0.8 V		3.0)	75		μA
hold current		lı (HOLD)	V _{IN} = 2.0 V	\rightarrow (a)	3.0	-75		μA
Bushold input over-c	drive current	lu (op)		(Note 1)	3.6		450	μA
to change state		I _{I (OD)}	(Note 2)		3.6		-450	μA
3-state output OFF s	state current	I _{OZ}	$V_{IN} \neq V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6		±10.0	μA
Power-off leakage c	urrent	IOFF	V _{OUT} = 0 to 3.6 V	\sim	0	_	10.0	μA
	rront		V _{IN} = V _{CC} or GND		2.7 to 3.6		20.0	
Quiescent supply cu	ITEIIL	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.7 to 3.6	_	±20.0	μA
Increase in I _{CC} per i	nput	Alcc	V _{IH} = V _{CC} – 0.6 V		2.7 to 3.6		750	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

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DC Characteristics (Ta = –40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	tics	Symbol	Test Co	ondition	N/ 00	Min	Max	Unit
					V _{CC} (V)	4.0		
Input voltage	H-level	VIH		_	2.3 to 2.7	1.6		V
	L-level	VIL		-	2.3 to 2.7	—	0.7	
H-level				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2		
	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -6 mA	2.3))2.0	_		
			I _{OH} = -12 mA	2.3	1.8	—		
Output voltage	it voltage			I _{OH} = -18 mA	2.3	1.7	_	V
L-level		vel V _{OL}		I _{OL} = 100 μA	2.3 to 2.7		0.2	
	L-level		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 18 \text{ mA}$	I _{OL} = 12 mA	2.3	_	0.4	
				2.3	\square	0.6		
Input leakage	(OE)	lu.	V _{IN} = 0 to 3.6 V		2.3 to 2.7	St -	±5.0	^
current	(An)	I _{IN}	$V_{IN} = V_{CC}$ or GND	(7)	2.3 to 2.7	\sum	>±5.0	μA
Bushold input minim	um drive	1	V _{IN} = 0.7 V		2.3	45) —	
hold current		II (HOLD)	V _{IN} = 1.6 V	\sim	2.3	-45	_	μA
Bushold input over-d	Irive current			(Note 1)	2.7	~	300	٨
to change state		I _{I (OD)}		(Note 2)	2.7	_	-300	μA
3-state output OFF s	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7	_	±10.0	μA
Power-off leakage cu	urrent	IOFF	V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
	rrant	1	VIN = VCC or GND		2.3 to 2.7	_	20.0	
Quiescent supply cu	rient	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.3 to 2.7		±20.0	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteris	tics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH			1.8 to 2.3	$0.7 \times V_{CC}$	_	V
mput voltage	L-level	VIL	_	_		_	$0.2 \times V_{CC}$	v
H-level	Vон	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	Vcc - 0.2	_		
Output voltage				$I_{OH} = -6 \text{ mA}$	71.8	1.4	_	v
L-le	L-level	V _{OL} V _{IN}	Ver Ver or Ve	I _{OL} = 100 μA	1.8	_	0.2	
	L-level		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 6 mA	1.8	_	0.3	
Input leakage	(OE)	lu i	V _{IN} = 0 to 3.6 V		1.8		±5.0	μA
current	(An)	l _{IN}	$V_{IN} = V_{CC}$ or GND		1.8	Æ	±5.0	μΑ
Bushold input minim	um drive		V _{IN} = 0.36 V		1.8	25	\geq	
hold current		II (HOLD)	V _{IN} = 1.26 V	$(7/5)^{\sim}$	1.8	-25	> _	μA
Bushold input over-d	Irive current	h (an)		(Note 1)	1.8	14	200	μA
to change state		I _{I (OD)}	(Note 2)		1.8	L.	-200	μΑ
3-state output OFF s	state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.8		±10.0	μΑ
Power-off leakage cu	urrent	IOFF	V _{OUT} = 0 to 3.6 V	\sim (7/	0	_	10.0	μA
	rrant	l	V _{IN} = V _{CC} or GND		1.8	_	20.0	
Quiescent supply cu	ment	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	1.8		±20.0	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500 \Omega$) (Note 1)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
\searrow	+		1.8	1.5	5.0	
Propagation delay time	t _{pLH} t _{pHL ∞}	Figure 1, Figure 2	2.5 ± 0.2	1.0	3.0	ns
	^{ophL}	~	$\textbf{3.3}\pm\textbf{0.3}$	0.8	2.5	
	4		1.8	1.5	6.5	
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.1	ns
	(tpZH) 3	$\textbf{3.3}\pm\textbf{0.3}$	0.8	3.5		
	+		1.8	1.5	5.0	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	3.8	ns
	^t pHZ		3.3 ± 0.3	0.8	3.5	
	•		1.8	_	0.5	
Output to output skew	t _{osLH}	(Note 2)	2.5 ± 0.2	_	0.5	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	_	0.5	

Note 1: For $C_L = 50 \text{ pF}$, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. (tool H = |tol Hm - tol Hn|, too H = |toH| m - to

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	0.25		
Quiet output maximum dynamic V _{OI}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	0.6	V	
		$V_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	(Note)	3.3	0.8		
		$V_{IH} = 1.8 \ V, \ V_{IL} = 0 \ V$	(Note)	1.8	-0.25		
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	-0.6	V	
,		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	-0.8		
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	1.5		
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	1.9	.9 V	
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	2.2		

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

					/	
Characteristics	Symbol	Test Condition	(C)	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		$\left(\right)$	1.8, 2.5, 3.3	6	pF
Output capacitance	CO		$(// \uparrow)$	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} ≠ 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

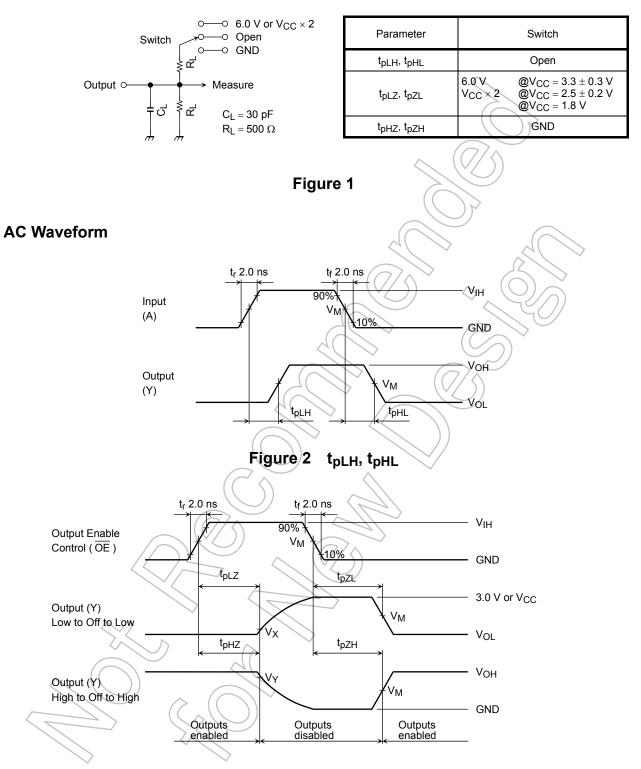
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

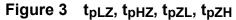
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 (per bit)$

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AC Test Circuit





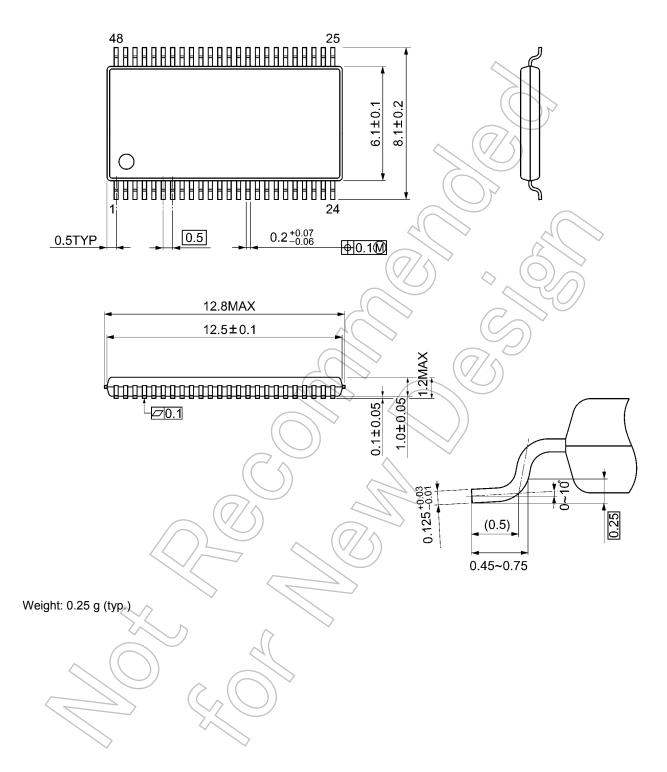
Symbol	V _{CC}		
	$3.3\pm0.3~V$	$2.5\pm0.2~V$	1.8 V
V _{IH}	2.7 V	V _{CC}	V _{CC}
V_{M}	1.5 V	V _{CC} /2	V _{CC} /2
V_{X}	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
V_{Y}	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V



Package Dimensions

TSSOP48-P-0061-0.50A

Unit: mm



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